1077

Bicyclo[1.1.0]tetragermane and Bicyclo[2.2.0]hexagermane; An *Ab Initio* Study of Bicyclic Germanium Compounds

Shigeru Nagase* and Mari Nakano

Department of Chemistry, Faculty of Education, Yokohama National University, Yokohama 240, Japan

By means of *ab initio* calculations, it is predicted that bicyclo[1.1.0]tetragermane exhibits a strong bond-stretch isomerism, whereas bicyclo[2.2.0]hexagermane adopts a normal structure with the four-membered rings fused.

There has been considerable recent interest in the preparation and characterization of the heavier atom analogues of bicycloalkanes. In the last three years derivatives of bicyclo[1.1.0]tetrasilane¹ and bicyclo[2.2.0]hexasilane² have been synthesized, and their X-ray structures have been determined.^{3,4} We report here the first *ab initio* calculations on bicyclo[1.1.0]tetragermane (1) and bicyclo[2.2.0]hexagermane (2), in continuance of our recent comparative study of the corresponding silicon compounds.⁵ Geometries were fully optimized at the Hartree-Fock (HF) level with the split-

Figure 1. Optimized geometries of cyclotrigermane (D_{3h}) and cyclotetragermane (D_{4h}) (in Å and degrees). The total energies are -6200.02939 and -8266.77912 a.u., respectively. No puckered D_{2d} form of cyclotetragermane was favoured, in contrast with C₄H₄ and Si₄H₄.





Figure 2. Optimized geometries of two isomers (a) and (b) of (1) $(C_{2\nu})$ (in Å and degrees). The inter-flap angles and total energies are 118.3° and -8265.56420 a.u. for (a) and 143.6° and -8265.58888 a.u. for (b).

valence 3-21G(*) basis set augmented by a set of d polarization functions (exponent 0.246) on Ge.⁶ For comparison, calculations were performed for the monocyclic germanium compounds, cyclotrigermane and cyclotetragermane, at the same theoretical level; these results are shown in Figure 1.

As Figure 2 shows, two distinctly different structures, (a) and (b), were located for (1), as for the silicon analogue. $^{5,7-9}$ Both have $C_{2\nu}$ symmetry. The peripheral Ge–Ge bond lengths in (a) and (b) are rather shorter than the Ge-Ge bond lengths in the three-membered ring of cyclotrigermane (Figure 1). The central Ge-Ge bridge bond (2.478 Å) in (a) is only 0.03 Å longer than the Ge-Ge bonds in cyclotrigermane. In sharp contrast, the central Ge-Ge bond in (b) is stretched to 3.025 Å and has some singlet diradical character. The stretching of ca. 0.5 Å is similar to that calculated recently for the corresponding silicon compound.^{5,7–9} However, the energy difference $(15.5 \text{ kcal mol}^{-1})$ favouring (b) over (a) is twice or three times larger in (1) than the corresponding HF/3-21G(*) value of 6 kcal mol⁻¹ for the silicon compound,⁷ suggesting the greater stability of the 'bond-stretch' isomer of the germanium compound.

The important geometrical differences between (a) and (b) lie not only in the central bond lengths, but also in the Ge-Ge-H angles at the bridgehead positions [142.5° (a) vs. 86.5° (b)]. The much smaller Ge-Ge-H angles in (b) enforce a



Figure 3. Optimized geometries of two $C_{2\nu}$ isomers (a) and (b) after methyl substitution (in Å and degrees). The inter-flap angles and total energies are 115.7° and -8343.23491 a.u. for (a) and 147.7° and -8343.24983 a.u. for (b).



Figure 4. Optimized geometries of (2) $(C_{2\nu})$ (in Å and degrees). The inter-flap angle and total energy are 107.1° and -12398.34469 a.u. Because of the size of the molecule, d polarization functions are included only on the bridgehead Ge atoms.

close approach of the two H atoms attached to the bridgeheads. It has recently been shown in the silicon compounds that methyl substitution at the bridgehead positions leads to a 'bond-short' normal isomer for steric and electronic reasons.^{7,9} Thus the two H atoms on the bridgeheads in (1) are replaced by methyl groups. As Figure 3 shows, however, two isomers were located and the bond-stretch isomer was calculated to be $9.4 \text{ kcal mol}^{-1}$ more stable even in 1,3-dimethylbicyclo[1.1.0]tetragermane.[‡] It is note-worthy that the methyl substitution has no significant effect on the central Ge–Ge bonds of the two isomers.[‡]

⁺ In a preliminary study, we have found that a similar ineffectiveness of methyl substitution results in the corresponding silicon compound, contrary to recent findings.^{7,9} This apparent discrepancy for the silicon compound is due to the fact that no geometry optimization was carried out in the previous studies.^{7,9}

[‡] In silicon compounds the same was also true for more bulky groups, though the bond-stretch isomers became gradually less stable.



As shown in Figures 2 and 3, the inter-flap angles between the fused three-membered rings are much larger in the bond-stretch isomers: 118.3° (a) vs. 143.6° (b) in (1) and 115.7° (a) vs. 147.7° (b) in the methyl substituted (1). This suggests that the bond stretch isomers may be viewed as a fourmembered monocyclic ring with a weak transannular bond [see (A)]: germanium has a tendency to prefer four-membered over three-membered rings.

 $[\text{GeH}_2]_n + n\text{H}_3\text{Ge-GeH}_3 \rightarrow n\text{H}_3\text{Ge-GeH}_2\text{-GeH}_3 (n = 3 \text{ or } 4)$ (i)

To confirm this view, we calculated the strain energies of cyclotrigermane $[GeH_2]_3$ and cyclotetragermane $[GeH_2]_4$ by use of the so-called homodesmotic reactions (i).¹⁰ The values obtained were 44.6 and 13.5 kcal mol⁻¹ for cyclotrigermane and cyclotetragermane, respectively. The strain energy difference of 31 kcal mol⁻¹ is larger than the value of 22 kcal mol⁻¹ between cyclotrisilane (39 kcal mol⁻¹) and cyclotetrasilane (17 kcal mol⁻¹).¹¹ This indicates that the difference in strain energy between four-membered rings and three-membered rings is significantly greater in germanium compounds than in silicon compounds; this forms an interesting contrast with the fact that these ring sizes are almost equally strained (*ca.* 27 kcal mol⁻¹) in carbon compounds.¹² It appears that germanium three-membered rings are least strained.

As expected from this property of germanium, only a normal structure was located for (2), consisting of fourmembered rings. As Figure 4 shows, the central and peripheral Ge–Ge bond lengths in (2) compare favourably with those in the four-membered ring of cyclotetragermane (Figure 1). In conclusion, the high strain in three-membered germanium rings (and the relatively weak Ge–Ge bonds as compared with C–C bonds) leads to bond-stretch isomerism in (1). On the other hand, compound (2) with its less strained four-membered rings fused, has a normal structure. As in silicon chemistry,¹⁻⁴ both structures (1) and (2) present interesting synthetic targets.

Calculations were carried out at the Computer Center of the Institute of Molecular Science and the Computer Room of the Faculty of Education of Yokohama National University using the GAUSSIAN 82 program.¹³ This work was in part supported by a grant from the Ministry of Education, Science, and Culture, Japan.

Received, 5th April 1988; Com. 8/01341A

References

- 1 S. Masamune, Y. Kabe, S. Collins, D. J. Williams, and R. Jones, J. Am. Chem. Soc., 1985, **107**, 5552.
- 2 H. Matsumoto, H. Miyamoto, N. Kojima, and Y. Nagai, J. Chem. Soc., Chem. Commun., 1987, 1316.
- 3 R. Jones, D. J. Williams, Y. Kabe, and S. Masamune, Angew. Chem., Int. Ed. Engl., 1986, 25, 173.
- 4 H. Matsumoto, H. Miyamoto, N. Kojima, Y. Nagai, and M. Goto, Chem. Lett., 1988, 629.
- 5 S. Nagase and T. Kudo, J. Chem. Soc., Chem. Commun., 1988, 54.
- 6 K. D. Dobbs and W. J. Hehre, *J. Comp. Chem.*, 1986, 7, 359; S. Huzinaga, J. Andzelm, M. Klobukowski, E. Radzio-Andzelm, Y. Sakai, and H. Tatewaki, 'Gaussian Basis Sets for Molecular Calculations,' Elsevier, New York, 1984.
- 7 P. v. R. Schleyer, A. F. Sax, J. Kalcher, and R. Janoschek, Angew. Chem., Int. Ed. Engl., 1987, 26, 364.
- 8 T. Dabisch and W. W. Schoeller, J. Chem. Soc., Chem. Commun., 1986, 896.
- 9 W. W. Schoeller, T. Dabisch, and T. Busch, *Inorg. Chem.*, 1987, 26, 4389.
- 10 P. George, M. Trachtman, C. W. Bock, and A. M. Brett, *Tetrahedron*, 1976, **32**, 317; A. Greenberg, and J. F. Liebman, 'Strained Organic Molecules,' Academic Press, New York, 1978.
- 11 S. Nagase, M. Nakano, and T. Kudo, J. Chem. Soc., Chem. Commun., 1987, 60.
- 12 K. B. Wiberg, Angew. Chem., Int. Ed. Engl., 1986, 25, 312.
- 13 J. S. Binkley, M. J. Frisch, D. J. DeFrees, K. Rahgavachari, R. A. Whiteside, H. B. Schlegel, E. M. Fludre, and J. A. Pople, 'GAUSSIAN 82', Department of Chemistry, Carnegie-Mellon University, Pittsburgh, USA.